NSN 5980-01-247-8986

Light Emitting Diode - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5980-01-247-8986

Inclosure Material:	
Plastic	
Overall Length:	
0.675 inches	
Overall Diameter:	
0.235 inches	
_ens Transparency:	
Translucent	
nternal Configuration:	
Point contact	
nternal Junction Configuration:	
'n	
Nounting Method:	
Press fit	
Criticality Code Justification:	
Żzzy	
Semiconductor Material:	
Sallium arsenide phosphide	
/oltage Rating In Volts Per Characteristic:	
2.2 forward voltage, dc	
Current Rating Per Characteristic:	
0.00 milliamperes source cutoff current preset	
Power Rating Per Characteristic:	
20.0 milliwatts small-signal input power, common-collector preset	
olor Tone Produced Per Source:	
ted lens	
Luminous Intensity:	
0.0 millicandela	
Aximum Operating Tempurature Per Measurement Point:	
00.0 degrees celsius ambient air	
Special Features:	
tem must comply with requirements of defense supply center columbus, production standard no. Lo3598	
Ferminal Type And Quantity:	
2 uninsulated wire lead	
Reference Number Differentiating Characteristics:	
Reference number differentiating material will be iaw naval inventory control point acitivity hx quality control, manufacturing and	d testing
specifications available at the dla icp	
Shelf Life:	
N/a	
Unit Of Measure:	
Unit Of Measure:	
Demilitarization:	

Yes - demil/mli

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